

# RJK0653DPB

60V, 45A, 4.8m $\Omega$  max. Silicon N Channel Power MOS FET Power Switching

R07DS0078EJ0200 Rev.2.00 Apr 09, 2013

### **Features**

- High speed switching
- Capable of 4.5 V gate drive
- Low drive current
- High density mounting

Low on-resistance

 $R_{DS(on)} = 3.8 \text{ m}\Omega \text{ typ. (at } V_{GS} = 10 \text{ V})$ 

- Pb-free
- Halogen-free

### **Outline**

RENESAS Package code: PTZZ0005DA-A (Package name: LFPAK)

5
D
4
G
7
1, 2, 3 Source
4 Gate
5 Drain

### **Application**

• Switching Mode Power Supply

### **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

| Item                                   | Symbol                      | Ratings     | Unit |
|--|-----------------------------|-------------|------|
| Drain to source voltage                | V <sub>DSS</sub>            | 60          | V    |
| Gate to source voltage                 | $V_{GSS}$                   | ±20         | V    |
| Drain current                          | I <sub>D</sub>              | 45          | A    |
| Drain peak current                     | I <sub>D(pulse)</sub> Note1 | 180         | A    |
| Body-drain diode reverse drain current | I <sub>DR</sub>             | 45          | A    |
| Avalanche current                      | I <sub>AP</sub> Note 2      | 22.5        | A    |
| Avalanche energy                       | E <sub>AS</sub> Note 2      | 38          | mJ   |
| Channel dissipation                    | Pch Note3                   | 65          | W    |
| Channel to Case Thermal Resistance     | θch-C                       | 1.92        | °C/W |
| Channel temperature                    | Tch                         | 150         | °C   |
| Storage temperature                    | Tstg                        | -55 to +150 | °C   |

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

2. Value at Tch = 25°C, Rg  $\geq$  50  $\Omega$ 

3. Tc = 25°C

This product is for the low voltage drive ( $\leq 10V$ ).

If the driving voltage is over 10 V under normal conditions, please use the product for high gate to source cutoff voltage  $(V_{GS(off)})$  which characteristics has been improved.

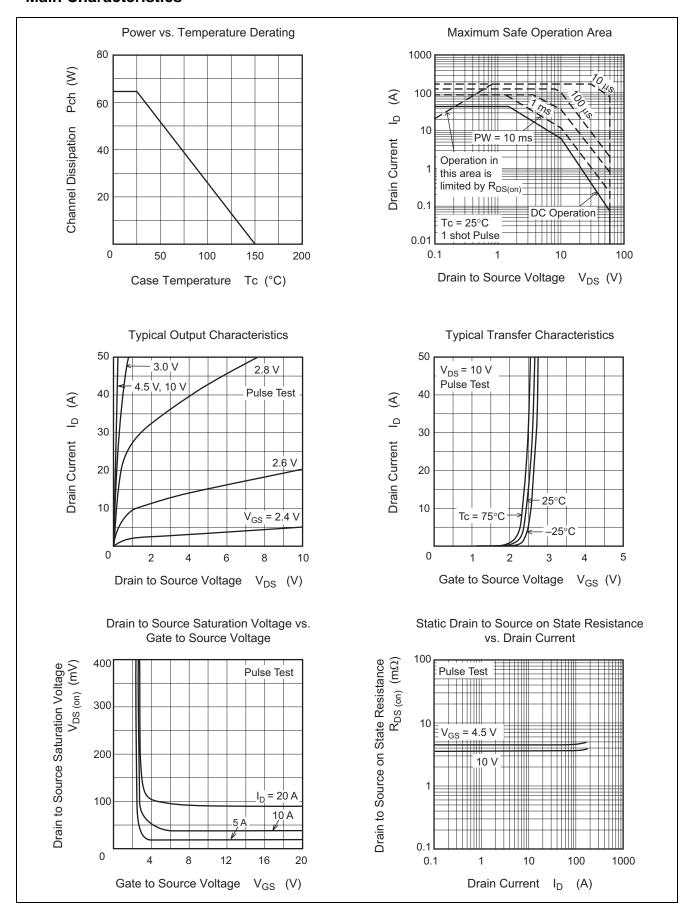
## **Electrical Characteristics**

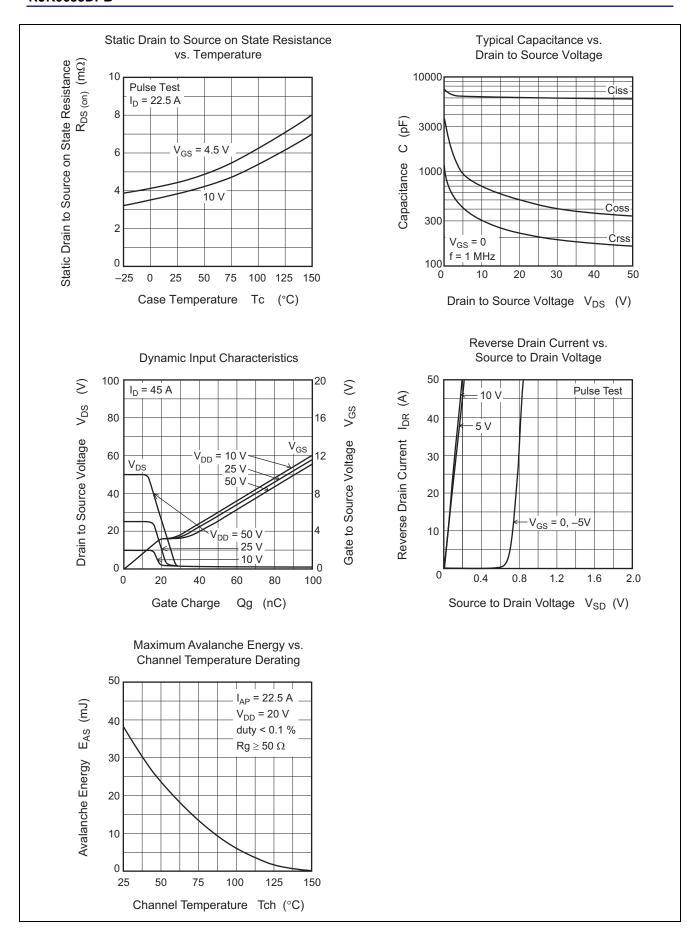
 $(Ta = 25^{\circ}C)$ 

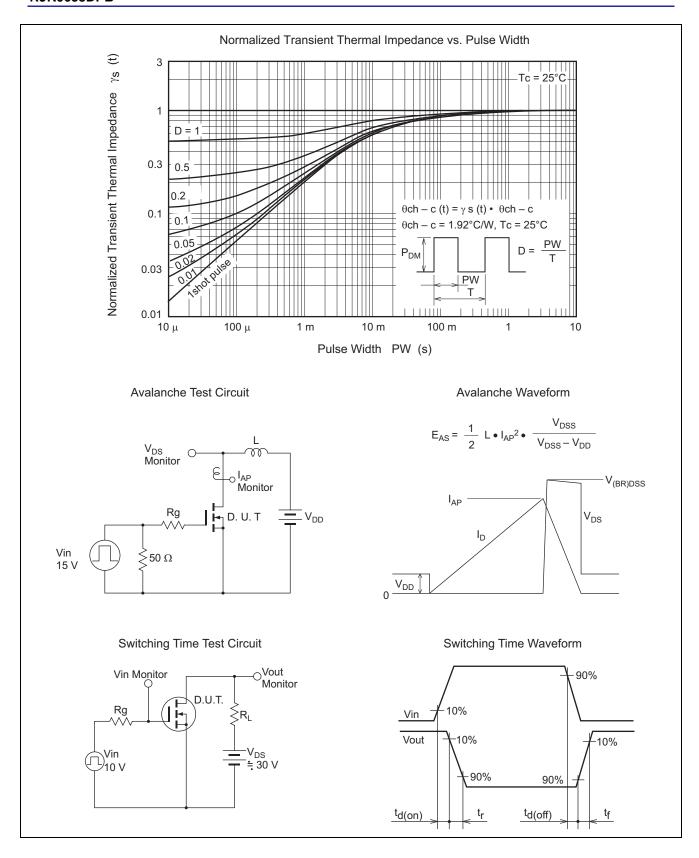
| Item                              | Symbol               | Min | Тур  | Max  | Unit | Test Conditions  |
|-----------------------------------|----------------------|-----|------|------|------|--|
| Drain to source breakdown voltage | V <sub>(BR)DSS</sub> | 60  | _    | _    | V    | $I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$  |
| Gate to source leak current       | I <sub>GSS</sub>     | _   | _    | ±0.1 | μΑ   | $V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$                                      |
| Zero gate voltage drain current   | I <sub>DSS</sub>     | -   | _    | 1    | μΑ   | $V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}$  |
| Gate to source cutoff voltage     | $V_{GS(off)}$        | 1.2 | _    | 2.5  | V    | $V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$  |
| Static drain to source on state   | R <sub>DS(on)</sub>  | _   | 3.8  | 4.8  | mΩ   | $I_D = 22.5 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note4}}$                           |
| resistance                        | R <sub>DS(on)</sub>  | _   | 4.5  | 6.1  | mΩ   | $I_D = 22.5 \text{ A}, V_{GS} = 4.5 \text{ V}^{\text{Note4}}$                          |
| Forward transfer admittance       | y <sub>fs</sub>      | _   | 110  | _    | S    | $I_D = 22.5 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note4}}$                           |
| Input capacitance                 | Ciss                 | _   | 6100 | _    | pF   | V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0 V,<br>f = 1 MHz                            |
| Output capacitance                | Coss                 | _   | 700  | _    | pF   |  |
| Reverse transfer capacitance      | Crss                 | _   | 300  | _    | pF   |  |
| Gate Resistance                   | Rg                   | _   | 0.5  | _    | Ω    |  |
| Total gate charge                 | Qg                   | _   | 42   | _    | nC   | $V_{DD} = 25 \text{ V}, V_{GS} = 4.5 \text{ V},$ $I_{D} = 45 \text{ A}$                |
| Gate to source charge             | Qgs                  | _   | 20   | _    | nC   |  |
| Gate to drain charge              | Qgd                  | _   | 11.8 | _    | nC   |  |
| Turn-on delay time                | t <sub>d(on)</sub>   | _   | 14   | _    | ns   | $V_{GS} = 10 \text{ V}, I_D = 22.5 \text{ A},$   |
| Rise time                         | t <sub>r</sub>       | _   | 8.3  | _    | ns   | $V_{DD} \cong 30 \text{ V}, \text{ R}_{L} = 1.33 \ \Omega,$ $\text{Rg} = 4.7 \ \Omega$ |
| Turn-off delay time               | t <sub>d(off)</sub>  | _   | 68   | _    | ns   |  |
| Fall time                         | t <sub>f</sub>       | _   | 14   | _    | ns   |  |
| Body-drain diode forward voltage  | $V_{DF}$             | _   | 0.83 | 1.1  | V    | $I_F = 45 \text{ A}, V_{GS} = 0 \text{ V}^{\text{Note4}}$                              |
| Body-drain diode reverse recovery | t <sub>rr</sub>      | _   | 40   | _    | ns   | I <sub>F</sub> = 45 A, V <sub>GS</sub> = 0 V   |
| time                              |                      |     |      |      |      | di <sub>F</sub> / dt = 100 A/ μs   |

Notes: 4. Pulse test

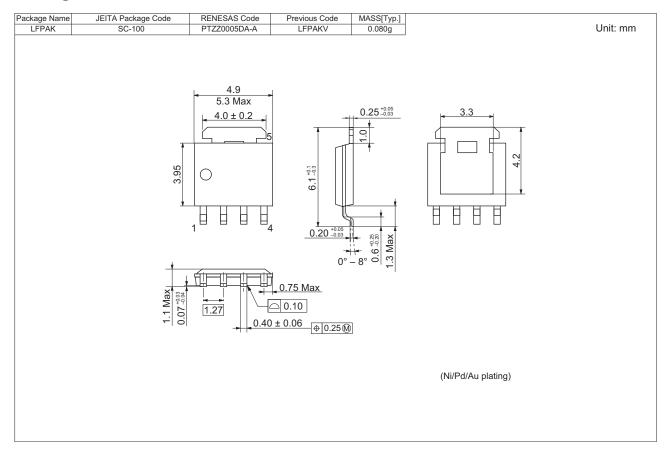
### **Main Characteristics**







## **Package Dimensions**



## **Ordering Information**

| Part No.         | Quantity | Shipping Container |
|------------------|----------|--------------------|
| RJK0653DPB-00-J5 | 2500 pcs | Taping             |

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